

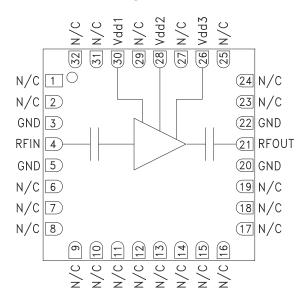


Typical Applications

The HMC565LC5 is ideal for use as a LNA or driver amplifier for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios & VSAT
- Test Equipment and Sensors
- Military & Space

Functional Diagram



HMC565LC5

GaAs SMT PHEMT LOW NOISE AMPLIFIER, 6 - 20 GHz

Features

Noise Figure: 2.5 dB Gain: 21 dB OIP3: 20 dBm Single Supply: +3V @ 53 mA 50 Ohm Matched Input/Output RoHS Compliant 5 x 5 mm Package

General Description

The HMC565LC5 is a high dynamic range GaAs PHEMT MMIC Low Noise Amplifier housed in a leadless RoHS compliant 5x5mm SMT package. Operating from 6 to 20 GHz, the HMC565LC5 features 21 dB of small signal gain, 2.5 dB noise figure and IP3 of +20 dBm across the operating band. This self-biased LNA is ideal for microwave radios due to its single +3V supply operation, and DC blocked RF I/O's.

Electrical Specifications, $T_{A} = +25^{\circ}$ C, Vdd 1, 2, 3 = +3V

| Parameter | Min. | Тур. | Max. | Min. | Тур. | Max. | Units |
|--|------|--------|-------|------|---------|-------|--------|
| Frequency Range | | 6 - 12 | | | 12 - 20 | | GHz |
| Gain | 19 | 21 | | 16 | 18.5 | | dB |
| Gain Variation Over Temperature | | 0.025 | 0.035 | | 0.025 | 0.035 | dB/ °C |
| Noise Figure | | 2.5 | 2.8 | | 2.5 | 3 | dB |
| Input Return Loss | | 15 | | | 12 | | dB |
| Output Return Loss | | 13 | | | 15 | | dB |
| Output Power for 1 dB Compression (P1dB) | 8 | 10 | | 9 | 11 | | dBm |
| Saturated Output Power (Psat) | | 11 | | | 13 | | dBm |
| Output Third Order Intercept (IP3) | | 20 | | | 21 | | dBm |
| Total Supply Current (Idd)(Vdd = +3V) | | 53 | 75 | | 53 | 75 | mA |

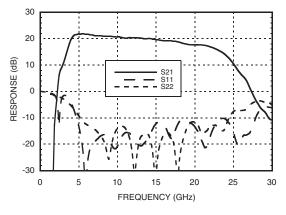


HMC565LC5

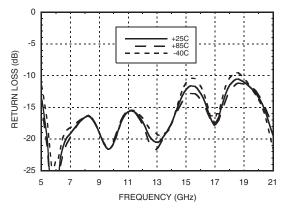
GaAs SMT PHEMT LOW NOISE AMPLIFIER, 6 - 20 GHz



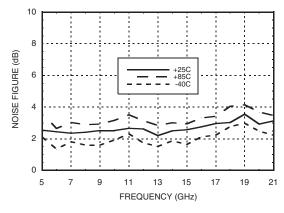
Broadband Gain & Return Loss



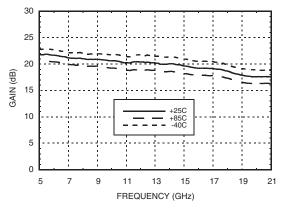
Input Return Loss vs. Temperature



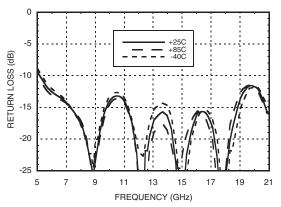
Noise Figure vs. Temperature



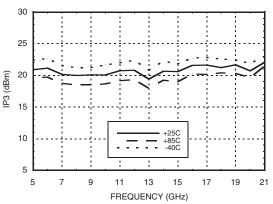




Output Return Loss vs. Temperature



Output IP3 vs. Temperature



For price, delivery, and to place orders, please contact Hittite Microwave Corporation: 20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com

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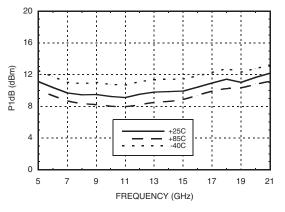




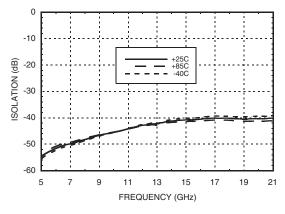
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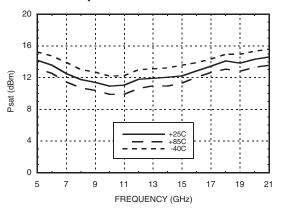




Reverse Isolation vs. Temperature

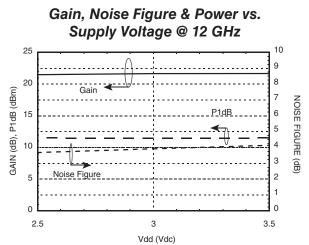


Psat vs. Temperature



Power Compression @ 12 GHz

INPUT POWER (dBm)



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ROHSV EARTH FRIENDLY

HMC565LC5

GaAs SMT PHEMT LOW NOISE AMPLIFIER, 6 - 20 GHz

Absolute Maximum Ratings

| Drain Bias Voltage (Vdd1, Vdd2, Vdd3) | +3.5 Vdc |
|---|----------------|
| RF Input Power (RFIN)(Vdd = +3.0 Vdc) | 0 dBm |
| Channel Temperature | 175 °C |
| Continuous Pdiss (T= 85 °C) (derate 8.5 mW/°C above 85 °C) | 0.753 W |
| Thermal Resistance (channel to ground paddle) | 119.5 °C/W |
| Storage Temperature | -65 to +150 °C |
| Operating Temperature | -40 to +85 °C |

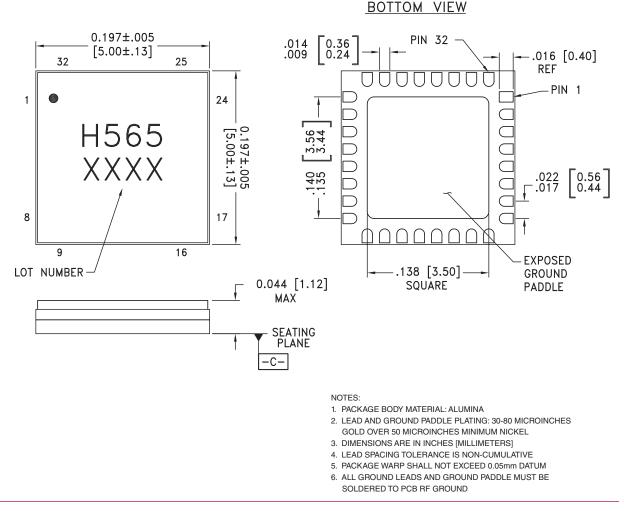
Typical Supply Current vs. Vdd

| Vdd (Vdc) | ldd (mA) | |
|-----------|----------|--|
| +2.5 | 51 | |
| +3.0 | 53 | |
| +3.5 | 56 | |



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

Outline Drawing



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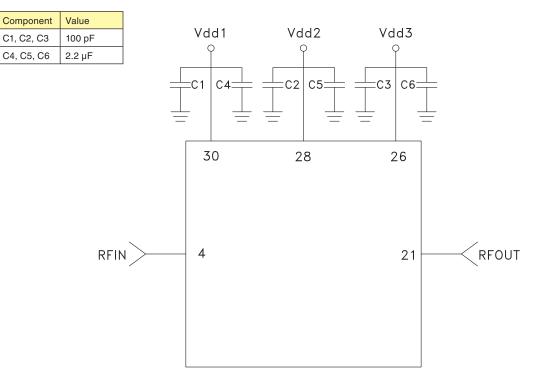
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ROHS V EARTH FRIENDLY

Pin Descriptions

| Pin Number | Function | Description | Interface Schematic |
|---|------------|--|---------------------|
| 1, 2, 6-19, 23-25, 27, 29, 31, 32 | N/C | This pin may be connected to RF/DC ground. Performance will not be affected. | |
| 3, 5, 20, 22 | GND | These pins and package bottom must be connected to RF/DC ground. | |
| 4 | RFIN | This pin is AC coupled and matched to 50 Ohms. | |
| 21 | RFOUT | This pin is AC coupled and matched to 50 Ohms. | |
| 30, 28, 26 | Vdd1, 2, 3 | Power Supply Voltage for the amplifier. External bypass capacitors of 100 pF and 2.2 μF are required. | • Vdd1,2,3 |

Application Circuit



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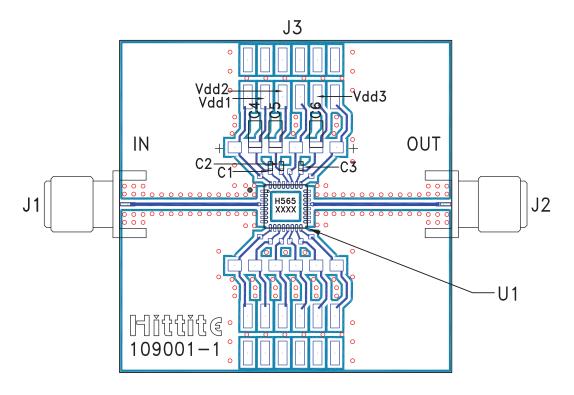


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Evaluation PCB



List of Materials for Evaluation PCB 110431 [1]

| Item | Description | |
|---------|-----------------------------|--|
| J1 - J2 | PCB Mount K Connector | |
| J3 | 2 mm DC Header | |
| C1 - C3 | 100 pF Capacitor, 0402 Pkg. | |
| C4 - C6 | 2.2 µF Capacitor, Tantalum | |
| U1 | HMC565LC5 Amplifier | |
| PCB [2] | 109001 Evaluation PCB | |

Reference this number when ordering complete evaluation PCB
Circuit Board Material: Rogers 4350

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request. 4